

ON Semiconductor® FDBL9406-F085

N-Channel PowerTrench[®] MOSFET

40 V, 240 A, 1.2 mΩ

Features

- Typical $R_{DS(on)}$ = 0.9 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 90 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems



MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240	•	
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	316	mJ	
P _D	Power Dissipation		300	W	
	Derate Above 25°C		2.0	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.5	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

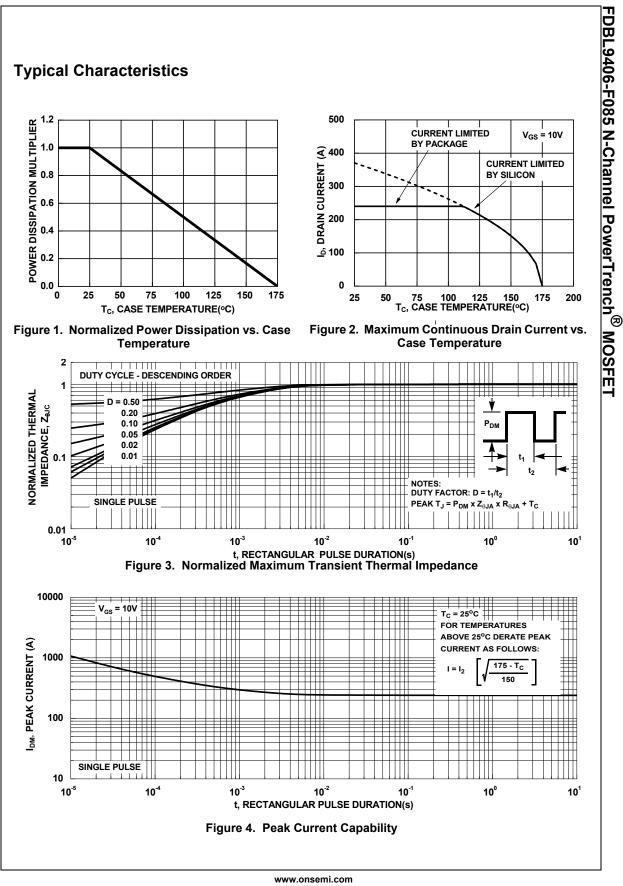
1: Current is limited by bondwire configuration.

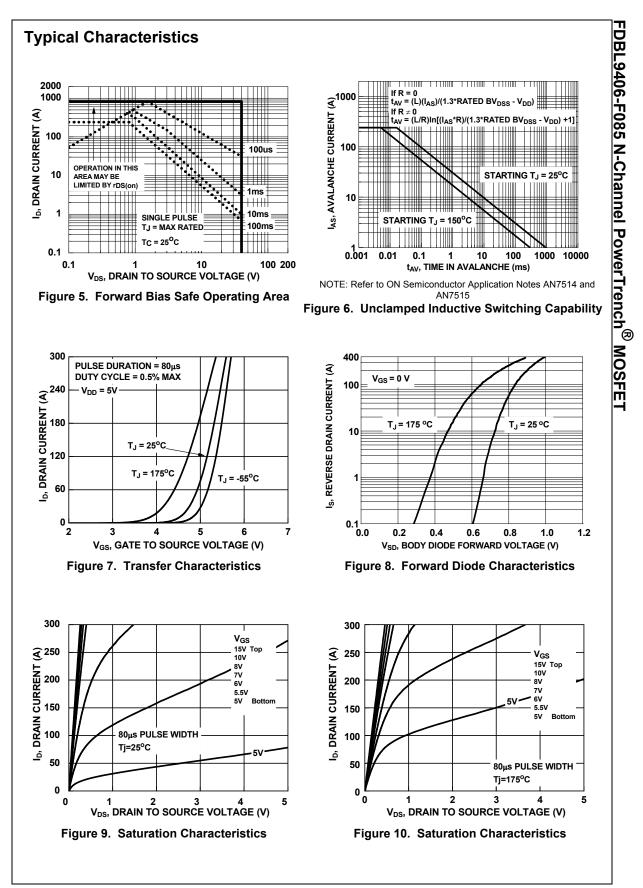
2: Starting T_J = 25°C, L = 0.1mH, I_{AS} = 79.5A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder moduling surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

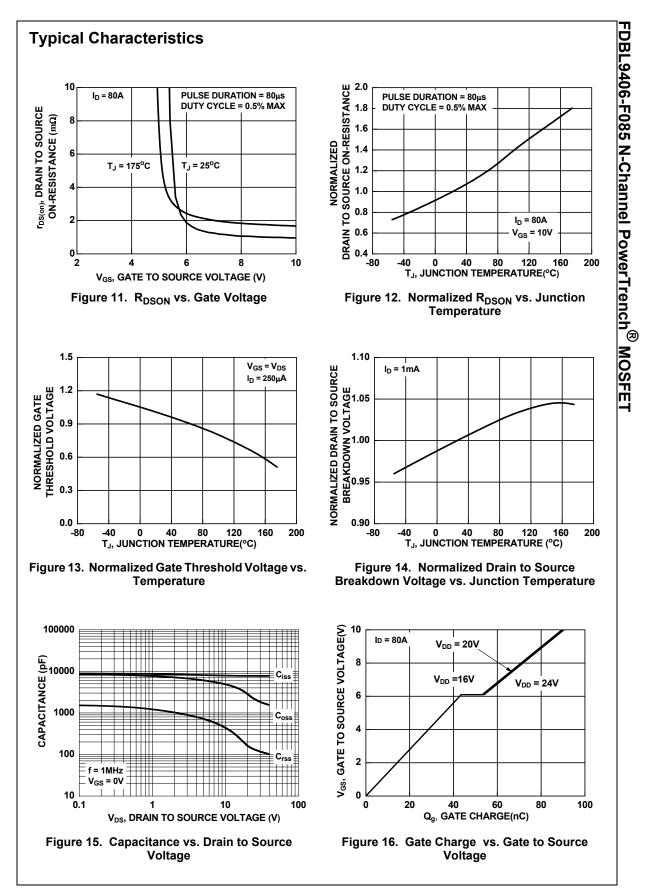
Device Marking	Device	Package			
FDBL9406	FDBL9406-F085	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	aracteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
		V_{DS} =40V, T_J =25°C		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$	T _J = 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.2	4.0	V
		I _D = 80A, V _{GS} = 10V	T _{.1} = 25 ^o C	-	0.90	1.20	mΩ
R _{DS(on)}	Drain to Source On Resistance		$T_{\rm J} = 175^{\rm o} {\rm C} \ ({\rm Note} \ 4)$	-	1.64	1.86	mΩ
-	ic Characteristics				1		
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	7735	-	pF
C _{oss}	Output Capacitance			-	2160	-	pF
C _{rss}	Reverse Transfer Capacitance			-	129	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.5	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 1		-	90	107	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2	V I _D = 80A	-	13.5	15.5	nC
Q _{gs}	Gate-to-Source Gate Charge	-		-	43	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	10	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	102	ns
t _{d(on)}	Turn-On Delay		-	-	33	-	ns
t _r	Rise Time	$V_{DD} = 20V, I_D = 80A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$		-	40	-	ns
t _{d(off)}	Turn-Off Delay			-	47	-	ns
t _f	Fall Time			-	23	-	ns
t _{off}	Turn-Off Time			-	-	91	ns
Drain-S	ource Diode Characteristics						
V.	Source to Drain Diade Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} = 40A, V _{GS} = 0V		-	-	1.2	V
	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs, V _{DD} =32V		-	91	107	ns
t _{rr}					128	167	nC





www.onsemi.com 4



ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor roducts, "ripcical" parameters which may be provided in ON Semiconductor data sheets and/or regardless of any support or applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products haranges, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application. Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, c

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

www.onsemi.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: FDBL9406-F085